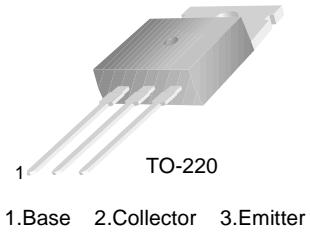




BD243/A/B/C

Medium Power Linear and Switching Applications

- Complement to BD244, BD244A, BD244B and BD244C respectively



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage : BD243 : BD243A : BD243B : BD243C	45 60 80 100	V
V_{CEO}	Collector-Emitter Voltage : BD243 : BD243A : BD243B : BD243C	45 60 80 100	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current (DC)	6	A
I_{CP}	*Collector Current (Pulse)	10	A
I_B	Base Current	2	A
P_C	Collector Dissipation ($T_C=25^\circ\text{C}$)	65	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{CEO(sus)}$	* Collector-Emitter Sustaining Voltage : BD243 : BD243A : BD243B : BD243C	$I_C=30\text{mA}$, $I_B=0$	45 60 80 100			V
I_{CEO}	Collector Cut-off Current : BD243/243A : BD243B/243C	$V_{CE} = 30\text{V}$, $I_B = 0$ $V_{CE} = 60\text{V}$, $I_B = 0$		0.7 0.7		mA
I_{CES}	Collector Cut-off Current : BD243 : BD243A : BD243B : BD243C	$V_{CE} = 45\text{V}$, $V_{BE} = 0$ $V_{CE} = 60\text{V}$, $V_{BE} = 0$ $V_{CE} = 80\text{V}$, $V_{BE} = 0$ $V_{CE} = 100\text{V}$, $V_{BE} = 0$		0.4 0.4 0.4 0.4		mA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 5\text{V}$, $I_C = 0$		1		mA
h_{FE}	*DC Current Gain	$V_{CE} = 4\text{V}$, $I_C = 0.3\text{A}$ $V_{CE} = 4\text{V}$, $I_C = 3\text{A}$	30 15			
$V_{CE(sat)}$	*Collector-Emitter Saturation Voltage	$I_C = 6\text{A}$, $I_B = 1\text{A}$			1.5	V
$V_{BE(on)}$	*Base-Emitter ON Voltage	$V_{CE} = 4\text{V}$, $I_C = 6\text{A}$			2	V

* Pulse Test : PW=300 μs , duty Cycle<20% Pulsed

Typical Characteristics

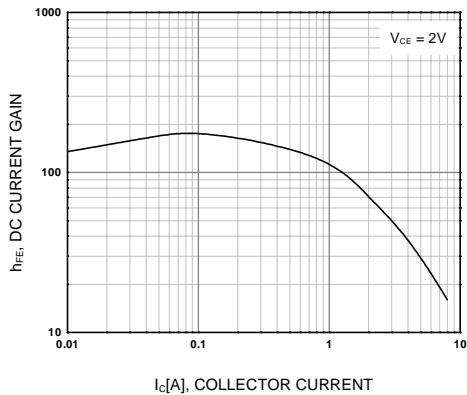


Figure 1. DC current Gain

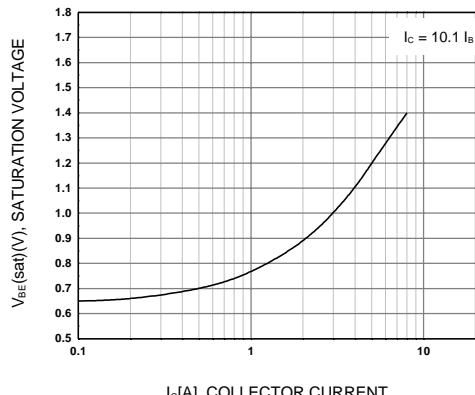


Figure 2. Base-Emitter Saturation Voltage

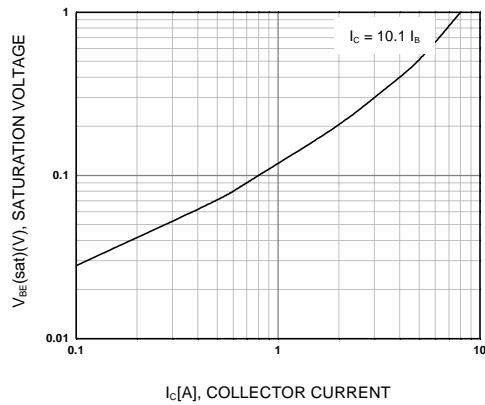


Figure 3. Collector-Emitter Saturation Voltage

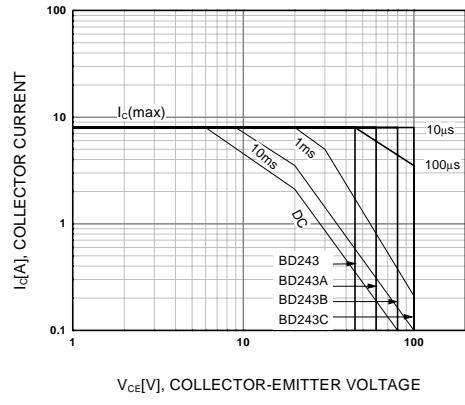


Figure 4. Safe Operating Area

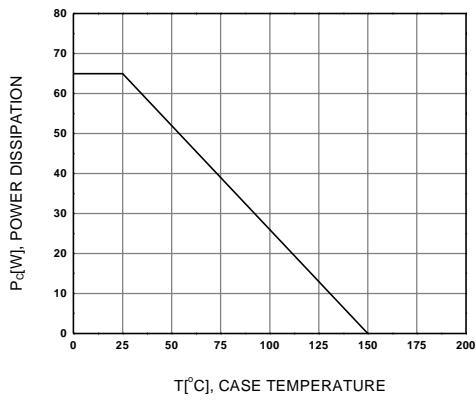
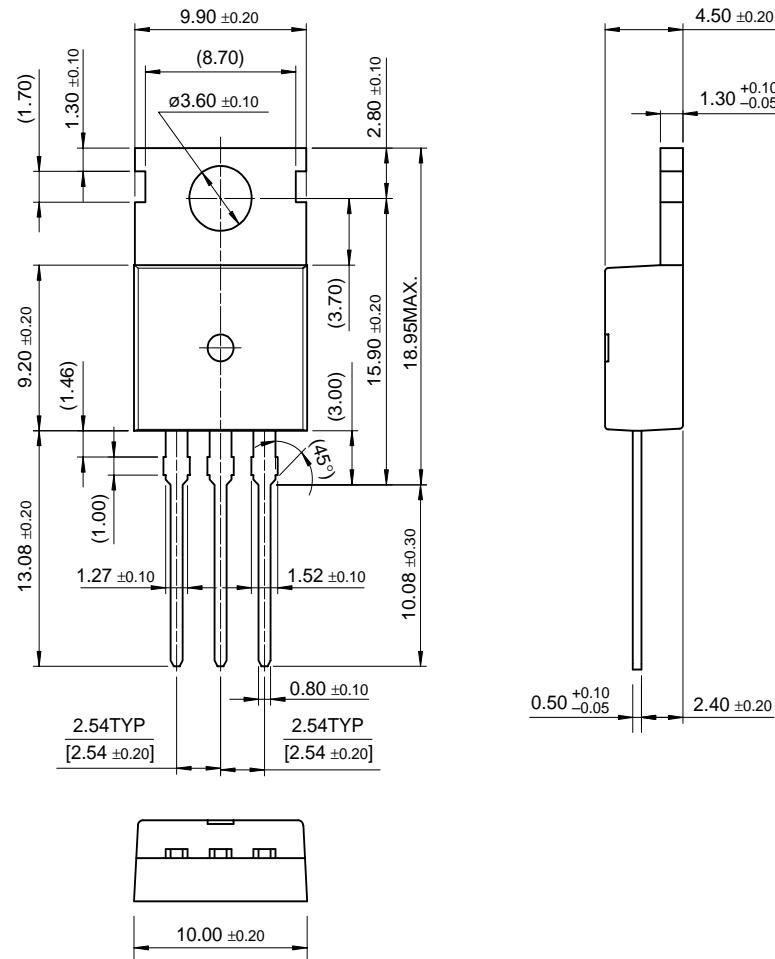


Figure 5. Power Derating

Package Demensions

TO-220



Dimensions in Millimeters

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